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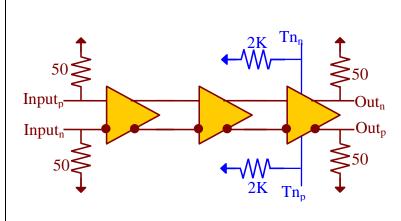
Ph. # 1-310-377-6029.

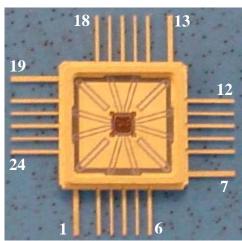
Fax # 1-310-377-9940.

ASNT5037-KMC 28Gbps Limiting Amplifier

- Broadband (DC-28*Gbps*) limiting amplifier featuring output signal amplitude adjustment from 0.0*V* to 1.0*V* single ended.
- Exhibits low jitter and limited temperature variation over industrial temperature range.
- 100MHz of bandwidth for the amplitude adjustment tuning port.
- Ideal for high speed proof-of-concept prototyping.
- Fully differential input and output buffers with on-chip 50Ω termination.
- CML output interface with nominal 500mV single-ended swing.
- Single -3.3*V* power supply.
- Power consumption: 510*mW*.
- Fabricated in SiGe for high performance, yield, and reliability.
- Custom CQFP 24-pin package.

DESCRIPTION





Functional Block Diagram

Package View

The temperature stable ASNT5037-KMC SiGe IC provides extremely low jitter broadband signal amplitude control capability between its input and output signal ports and is intended for use in high-speed measurement / test equipment. ASNT5037-KMC can process an up to 28Gbps data signal and deliver output signal amplitudes between 0.0V-1.0V through the up to 100MHz external adjustment of its differential tuning port. The part's I/Os support the CML logic interface with on chip 50Ω termination and may be used differentially, AC/DC coupled, single-ended, or in any combination. It operates from a single -3.3V power supply.

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TERMINAL FUNCTIONS

TERMINAL		TYPE	DESCRIPTION		
NAME	(NO.)				
vcc	2-4,6,8,10,12	PS	Power Supply: 0V		
14,16-18,20,22,24					
vee	1,7,13,19	PS	Power Supply: -3.3V		
inp	21	Input	Differential CML high-speed data signal inputs		
inn	23	•			
outp	11	Output	Differential CML high-speed data signal outputs		
outn	9	•			
tnp	5	Input	Differential high-speed amplitude adjustment tuning inputs		
tnn	15				

ELECTRICAL CHARACTERISTICS

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS			
VEE	-3.1	-3.3	-3.5	V	±6%			
VCC*		0.0		V				
IEE*		155		mA				
Power		510		mW				
Junction Temp.	-25	50	125	°C				
Input (in)								
Frequency	0.0		28	Gbps				
CM Level	Vcc-0.8	Vcc-0	.2 Vcc	V				
Swing (Diff or SE)	50	400	1000	mV	Peak-to-Peak			
Output (out)								
Frequency	0.0		28	Gbps				
CM Level*	Vcc-0.3	Vcc-0.2	5 Vcc-0.2	V				
SE Swing*	475	500	525	mV	Peak-to-Peak			
Rise/Fall Times*	10	12	14	ps	20%-80%			
Additive Jitter		TBD		ps	Peak-to-Peak			
Tuning Port (tn)								
Diff. Swing	-500		500	mV	Peak-to-Peak			
CM Level	Vcc-0.5	Vcc-0.2	25 Vcc	V				
Amplitude Variation	0.0	500	1000	mV				
CM Level	Vcc-0.5	Vcc-0	.25 Vcc	V				
Bandwidth	0.0		100	MHz				
* Tuning pins are not connected (NC)								

PACKAGE INFORMATION

The chip is packaged in ADSANTEC's custom 24-pin metal-ceramic package (CQFP). The package's mechanical information is available on the company's <u>website</u>.